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Memory Products	

82S185A

8K-bit TTL bipolar PROM

DESCRIPTION

The 82S185A is field programmable, which means that custom patterns are immediately available by following the Signetics Generic I fusing procedure. The devices are supplied with all outputs at logical Low. Outputs are programmed to a logic High level at any specified address by fusing the Ni-Cr link matrix.

This device includes on-chip decoding and one Chip Enable input for memory expansion. It features 3-State outputs for optimization of word expansion in bused organizations.

Ordering information can be found on the following page.

The 82S185A device is also processed to military requirements for operation over the military temperature range. For specifications and ordering information consult the Signetics Military Data Handbook.

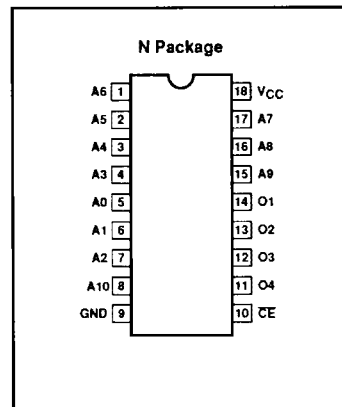
FEATURES

- Low power dissipation: 70μW/bit typ
- Address access time: 50ns max
- Input loading: -100μA max
- On-chip address decoding
- No separate fusing pins
- Unprogrammed outputs are Low level
- Fully TTL compatible
- One Chip Enable input
- Outputs: 3-State

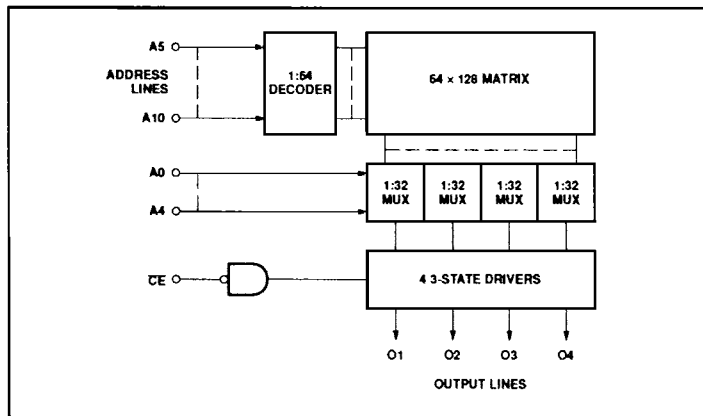
APPLICATIONS

- Microprogramming
- Control store
- Random logic
- Code conversion

PIN CONFIGURATION



BLOCK DIAGRAM



8K-bit TTL bipolar PROM (2048 × 4)**82S185A****ORDERING INFORMATION**

DESCRIPTION	ORDER CODE
18-Pin Plastic Dual-In-Line 300mil-wide	N82S185A N

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
V_{CC}	Supply voltage	+7.0	V_{DC}
V_{IN}	Input voltage	+5.5	V_{DC}
V_O	Output voltage Off-State	+5.5	V_{DC}
T_{amb}	Operating temperature range	0 to +75	°C
T_{stg}	Storage temperature range	-65 to +150	°C

DC ELECTRICAL CHARACTERISTICS0°C ≤ T_{amb} ≤ +75°C, 4.75V ≤ V_{CC} ≤ 5.25V

SYMBOL	PARAMETER	TEST CONDITIONS ^{1,2}	LIMITS			UNIT
			Min	Typ ³	Max	
Input voltage						
V _{IL}	Low	V _{CC} = 4.75V	2.0		0.8	V
V _{IH}	High	V _{CC} = 5.25V			V	
V _{IC}	Clamp	I _{IN} = -12mA			V	
Output voltage						
V _{OL}	Low	CE = Low	2.4		0.45	V
V _{OH}	High	I _{OUT} = 16mA				V
		I _{OUT} = -2mA				V
Input current						
I _{IL}	Low	V _{IN} = 0.45V			-100	μA
I _{IH}	High	V _{IN} = 5.5V			40	μA
Output current						
I _{OZ}	Hi-Z state	CE = High, V _{OUT} = 0.5V	-15		-40	μA
I _{OS}	Short circuit ⁴	CE = High, V _{OUT} = 5.5V			40	μA
		CE = Low, V _{OUT} = 0V, High stored			-70	mA
Supply current ⁵						
I _{CC}		V _{CC} = 5.25V		110	155	mA
Capacitance						
C _{IN}	Input	CE = High, V _{CC} = 5.0V		5		pF
C _{OUT}	Output	V _{IN} = 2.0V				8
		V _{OUT} = 2.0V				

NOTES:

1. Positive current is defined as into the terminal referenced.
2. All voltages with respect to network ground.
3. All typical values are at $V_{CC} = 5V$, $T_{amb} = +25^\circ C$.
4. Duration of short circuit should not exceed 1 second.
5. Measured with all inputs grounded and all outputs open.

8K-bit TTL bipolar PROM (2048 × 4)

82S185A

AC ELECTRICAL CHARACTERISTICS

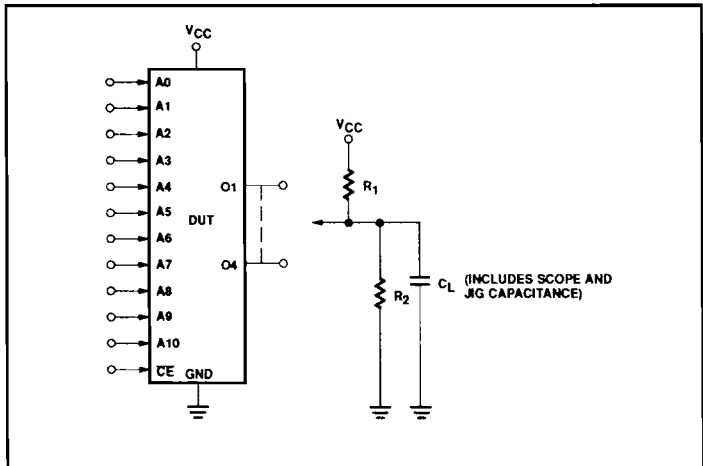
$R_1 = 270\Omega$, $R_2 = 600\Omega$, $C_L = 30\text{pF}$, $0^\circ\text{C} \leq T_{\text{amb}} \leq +75^\circ\text{C}$, $4.75\text{V} \leq V_{\text{CC}} \leq 5.25\text{V}$

SYMBOL	PARAMETER	TO	FROM	LIMITS			UNIT
				Min	Typ ¹	Max	
Access time ²							
t _{AA}		Output	Address		40	50	ns
t _{CE}		Output	Chip Enable		20	30	ns
Disable time ³							
t _{CD}		Output	Chip Disable		20	30	ns

NOTES:

- 1. Typical values are at $V_{\text{CC}} = 5\text{V}$, $T_{\text{amb}} = +25^\circ\text{C}$.
- 2. Tested at an address cycle time of $1\mu\text{s}$.
- 3. Measured at a delta of 0.5V from Logic Level with $R_1 = 750\Omega$, $R_2 = 750\Omega$, $C_L = 5\text{pF}$.

TEST LOAD CIRCUIT



VOLTAGE WAVEFORMS

